SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIER REVERSE VOLTAGE 50 to 1000 Volts FORWARD CURRENT 2.0 Ampere

SMAF

.051(1.30) .043(1.10)

106(2.7)

.094(2.4)

FEATURES

For surface mounted applications Low profile package Glass Passivated Chip Junction Easy to pick and place Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

Case: SMAF Terminals: Solderable per MIL-STD-750, Method 2026 Approx.Weight: 27mg / 0.00095oz

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 $^\circ\!\!\!\!\!^\circ\!\!\!\!^\circ$ ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load derate current by 20%

Dimensions in inches and (millimeters)

.051(1.3)

.039(1.0

.146(3.7) .130(3.3)

.193(4.9)

063(1.6

.009(0.23) .007(0.18)

S2A THRU S2M

PARAMETER		SYMBOL	S2A	S2B	S2D	S2G	S2J	S2K	S2M	UNIT
Maximum Repetitive Peak Reverse Voltage		Vrrm	50	100	200	400	600	800	1000	VOLTS
Maximum RMS Voltage		Vrms	35	70	140	280	420	560	700	VOLTS
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	VOLTS
Maximum Average Forward Rectified Current At T_{A} =65 $^{\circ}\!\!\!\!\!^{\circ}\!\!\!\!^{\circ}$		(AV)	2.0							Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	55							Amps
Maximum instantaneous forward voltage per at 2.0A		V _F	1.1							VOLTS
Maximum DC Reverse Current at Rated DC blocking voltage	T _A =25℃		5.0							uA
	T _A =125℃	R	100							
Typical Junction Capacitance (Measured at 1.0MHz and applied reverse voltage of 4.0V)		CJ	30							pF
Typical Thermal Resistance		Reja	85							°C /W
Operating Junction Temperature		TJ	-55 to +150							°C
Storage Temperature Rang		Tstg	-55 to +150							°C

1- Thermal resistance from Junction to ambient and from junction to lead mounted on P.C.B. with $0.2 \times 0.2''$ (5.0 \times 5.0mm) copper pad areas.

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RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve

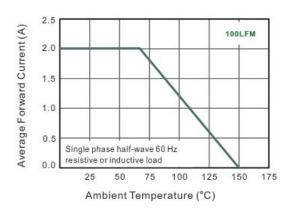
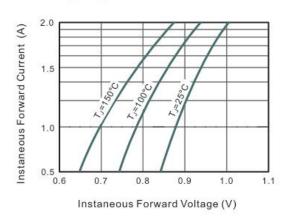
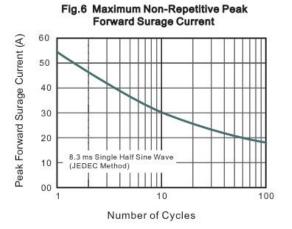


Fig.3 Typical Forward Characteristic





Note: Specifications are subject to change without notice.

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Fig.4 Typical Junction Capacitance

400

Instaneous Reverse Voltage (V)

200

Fig.2 Typical Instaneous Reverse Characteristics

150°C

T_=125°C

T_=100°C

600

800

S2A THRU

100

10

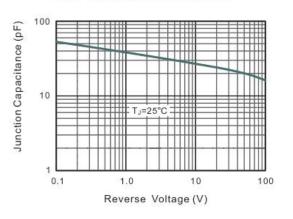
1.0

0.1

0.01

0

Instaneous Reverse Current (µA)



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